

74LVC1G3157

2-channel analog multiplexer/demultiplexer

Rev. 01 — 7 February 2005

Product data sheet

1. General description

The 74LVC1G3157 is a high-performance, low-power, low-voltage, Si-gate CMOS device that provides superior performance to most advanced CMOS compatible TTL families.

The 74LVC1G3157 provides one analog multiplexer/demultiplexer with one digital select input (S), two independent inputs/outputs (B1 and B2) and a common input/output (A).

2. Features

- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON-resistance:
 - ◆ 7.5 Ω (typical) at $V_{CC} = 2.7$ V
 - ◆ 6.5 Ω (typical) at $V_{CC} = 3.3$ V
 - ◆ 6 Ω (typical) at $V_{CC} = 5$ V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
 - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- CMOS low-power consumption
- Latch-up performance meets requirements of JESD 78 Class I
- Direct interface with TTL levels
- Control input accepts voltages up to 5 V
- Multiple package options
- Specified from -40 °C to $+85$ °C and from -40 °C to $+125$ °C

3. Quick reference data

Table 1: Quick reference data

$GND = 0$ V; $t_r = t_f \leq 2.5$ ns; minimum and maximum values at $T_{amb} = -40$ °C to $+85$ °C; typical values at $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{PZH} , t_{PZL}	turn-on time S to Bn	$C_L = 50$ pF; $R_L = 500$ Ω				
		$V_{CC} = 3.3$ V	0.5	4.0	5.5	ns
		$V_{CC} = 5.0$ V	0.5	3.0	4.0	ns
t_{PHZ} , t_{PLZ}	turn-off time S to Bn	$C_L = 50$ pF; $R_L = 500$ Ω				
		$V_{CC} = 3.3$ V	0.5	3.6	4.5	ns
		$V_{CC} = 5.0$ V	0.8	2.9	3.5	ns

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Table 1: Quick reference data ...continued
 $GND = 0\text{ V}$; $t_r = t_f \leq 2.5\text{ ns}$; minimum and maximum values at $T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$; typical values at $T_{amb} = 25\text{ }^{\circ}\text{C}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C_I	select input capacitance		-	2.5	-	pF
C_S	switch capacitance	OFF-state	-	6.0	-	pF
		ON-state	-	18	-	pF

4. Ordering information

Table 2: Ordering information

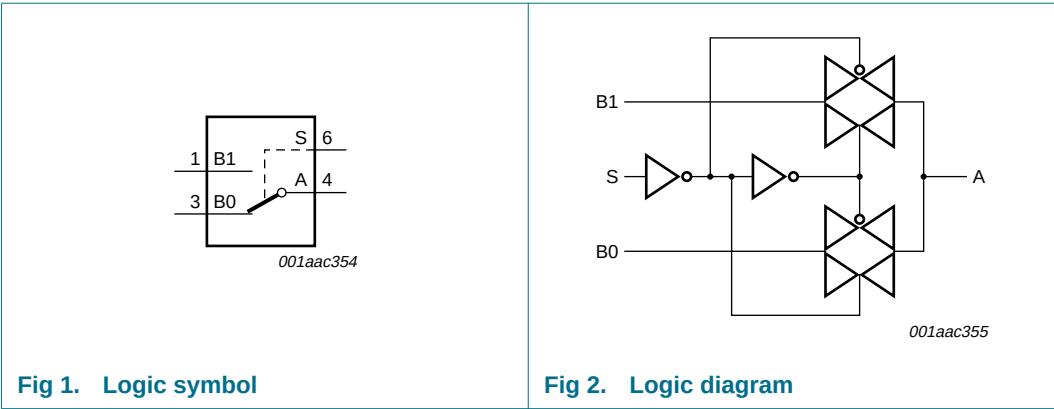
Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G3157GW	-40 °C to +125 °C	SC-88	plastic surface mounted package; 6 leads	SOT363
74LVC1G3157GV	-40 °C to +125 °C	SC-74	plastic surface mounted package; 6 leads	SOT457
74LVC1G3157GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886

5. Marking

Table 3: Marking

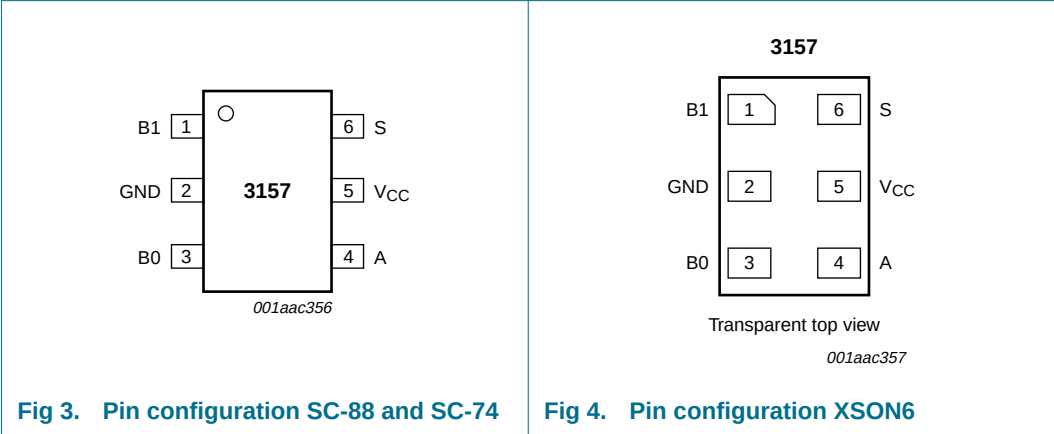
Type number	Marking code
74LVC1G3157GW	YJ
74LVC1G3157GV	YJ
74LVC1G3157GM	YJ

6. Functional diagram



7. Pinning information

7.1 Pinning



7.2 Pin description

Table 4: Pin description

Symbol	Pin	Description
B1	1	independent B1 input or output
GND	2	ground (0 V)
B0	3	independent B0 input or output
A	4	common A output or input
V _{CC}	5	supply voltage
S	6	select input

8. Functional description

8.1 Function table

Table 5: Function table [\[1\]](#)

Input S	Channel on
L	B0
H	B1

[1] H = HIGH voltage level;
L = LOW voltage level.

9. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
V_I	input voltage		^[1] -0.5	+6.5	V
I_{IK}	input diode current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5$	-	-50	mA
I_{SK}	switch diode current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5$	-	±50	mA
V_S	switch DC voltage	enable and disable mode	-0.5	$V_{CC} + 0.5$	V
I_S	switch source or sink current	$V_S > -0.5\text{ V}$ or $V_S < V_{CC} + 0.5$	-	±50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	±100	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40\text{ °C to }+125\text{ °C}$	-	300	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 7: Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
V_I	input voltage		0	-	5.5	V
V_S	switch DC voltage	enable and disable mode	^[1] 0	-	V_{CC}	V
T_{amb}	ambient temperature		-40	-	+125	°C
t_r, t_f	input rise and fall times	$V_{CC} = 1.65\text{ V to }2.7\text{ V}$	^[2] 0	-	20	ns/V
		$V_{CC} = 2.7\text{ V to }5.5\text{ V}$	^[2] 0	-	10	ns/V

[1] To avoid drawing V_{CC} current out of terminal A when switch current flows in terminal Bn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal A, no V_{CC} current will flow out of terminal Bn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

11. Static characteristics

Table 8: Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = -40\text{ °C to }+85\text{ °C}$ ^[1]						
V_{IH}	HIGH-level input voltage	$V_{CC} = 1.65\text{ V to }1.95\text{ V}$	$0.65V_{CC}$	-	-	V
		$V_{CC} = 2.3\text{ V to }2.7\text{ V}$	1.7	-	-	V
		$V_{CC} = 3\text{ V to }3.6\text{ V}$	2.0	-	-	V
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	$0.7V_{CC}$	-	-	V

Table 8: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V	-	-	0.3V _{CC}	V
I _{LI}	input leakage current on pin S	V _I = 5.5 V or GND; V _{CC} = 5.5 V	-	±0.1	±2	μA
I _{S(OFF)}	analog switch OFF-state current per channel	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; V _{CC} = 5.5 V; see Figure 5	-	±0.1	±5	μA
I _{S(ON)}	analog switch ON-state current per channel	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; V _{CC} = 5.5 V; see Figure 6	-	±0.1	±5	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; V _S = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V	-	0.1	10	μA
ΔI _{CC}	additional quiescent supply current pin S	V _I = V _{CC} – 0.6 V; V _S = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V	-	5	500	μA
C _I	input capacitance		-	2.5	-	pF
C _S	switch capacitance	OFF-state	-	6.0	-	pF
		ON-state	-	18	-	pF
T _{amb} = –40 °C to +125 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V _{CC} = 3 V to 3.6 V	2.0	-	-	V
		V _{CC} = 4.5 V to 5.5 V	0.7V _{CC}	-	-	
V _{IL}	LOW-level input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3 V to 3.6 V	-	-	0.8	V
		V _{CC} = 4.5 V to 5.5 V		-	0.3V _{CC}	V
I _{LI}	input leakage current on pin S	V _I = 5.5 V or GND; V _{CC} = 5.5 V	-	-	±10	μA
I _{S(OFF)}	analog switch OFF-state current per channel	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; V _{CC} = 5.5 V; see Figure 5	-	-	±20	μA
I _{S(ON)}	analog switch ON-state current per channel	V _I = V _{IH} or V _{IL} ; V _S = V _{CC} – GND; V _{CC} = 5.5 V; see Figure 6	-	-	±20	μA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; V _S = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V	-	-	40	μA
ΔI _{CC}	additional quiescent supply current pin S	V _I = V _{CC} – 0.6 V; V _S = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V	-	-	5000	μA

[1] Typical values are measured at $T_{amb} = 25\text{ }^{\circ}\text{C}$.

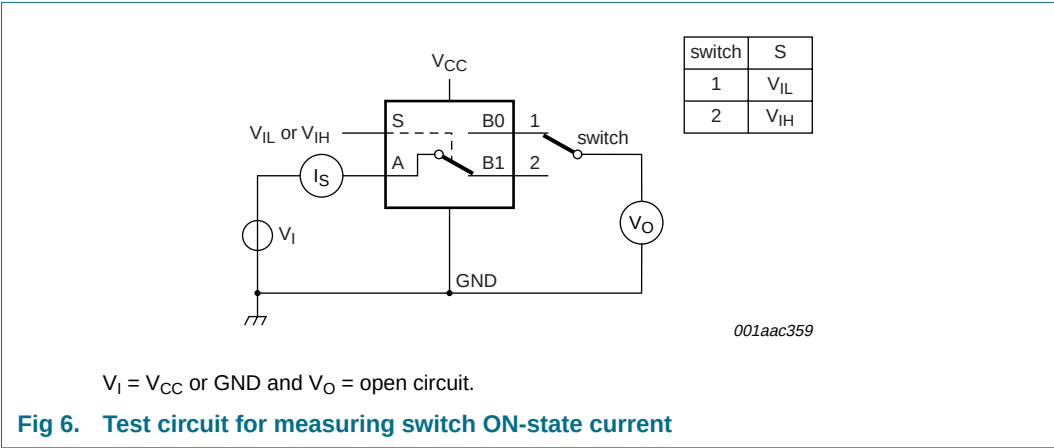
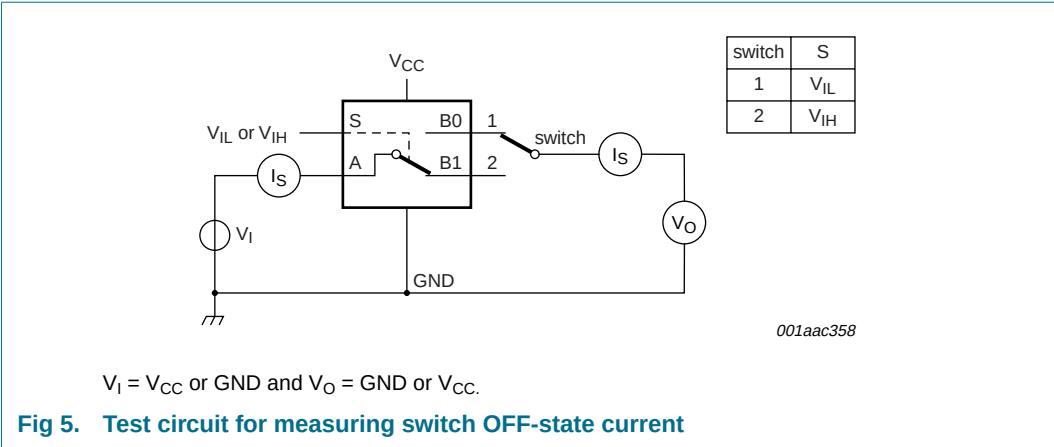


Table 9: Resistance R_{ON}

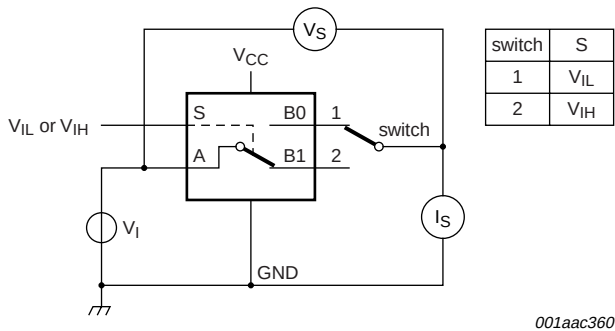
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); see test circuit [Figure 7](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ [1]						
$R_{ON(rail)}$	switch ON-state resistance (rail)	$V_S = GND; V_I = V_{IH}$				
		$I_S = 4\text{ mA}; V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	8.7	18	Ω
		$I_S = 8\text{ mA}; V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	7.2	16	Ω
		$I_S = 12\text{ mA}; V_{CC} = 2.7\text{ V}$	-	7.0	14	Ω
		$I_S = 24\text{ mA}; V_{CC} = 3\text{ V to }3.6\text{ V}$	-	6.5	12	Ω
		$I_S = 32\text{ mA}; V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	5.9	10	Ω
		$V_S = V_{CC}; V_I = V_{IH}$				
		$I_S = 4\text{ mA}; V_{CC} = 1.65\text{ V to }1.95\text{ V}$	-	12	30	Ω
		$I_S = 8\text{ mA}; V_{CC} = 2.3\text{ V to }2.7\text{ V}$	-	8.3	20	Ω
		$I_S = 12\text{ mA}; V_{CC} = 2.7\text{ V}$	-	7.8	18	Ω
		$I_S = 24\text{ mA}; V_{CC} = 3\text{ V to }3.6\text{ V}$	-	6.7	15	Ω
		$I_S = 32\text{ mA}; V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	5.2	10	Ω

Table 9: Resistance R_{ON} ...continuedAt recommended operating conditions; voltages are referenced to GND (ground = 0 V); see test circuit [Figure 7](#).

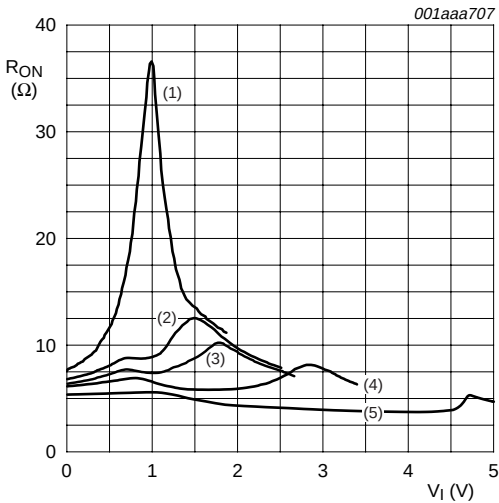
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R _{ON(peak)}	switch ON-state resistance (peak)	V _S = GND to V _{CC} ; V _I = V _{IH}				
		I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	57	140	Ω
		I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	15	40	Ω
		I _S = 12 mA; V _{CC} = 2.7 V	-	13	25	Ω
		I _S = 24 mA; V _{CC} = 3 V to 3.6 V	-	9.0	20	Ω
		I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	6.0	15	Ω
R _{ON(flatness)}	switch ON-resistance (flatness)	V _S = GND to V _{CC} ; V _I = V _{IH} ; see Figure 9				
		I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	100	-	Ω
		I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	17	-	Ω
		I _S = 12 mA; V _{CC} = 2.7 V	-	10	-	Ω
		I _S = 24 mA; V _{CC} = 3 V to 3.6 V	-	5	-	Ω
		I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	3	-	Ω
T _{amb} = -40 °C to +125 °C						
R _{ON(rail)}	switch ON-state resistance (rail)	V _S = GND; V _I = V _{IH}				
		I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	-	27	Ω
		I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	-	24	Ω
		I _S = 12 mA; V _{CC} = 2.7 V	-	-	21	Ω
		I _S = 24 mA; V _{CC} = 3 V to 3.6 V	-	-	18	Ω
		I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	-	15	Ω
		V _S = V _{CC} ; V _I = V _{IH}				
		I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	-	45	Ω
		I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	-	30	Ω
		I _S = 12 mA; V _{CC} = 2.7 V	-	-	27	Ω
		I _S = 24 mA; V _{CC} = 3 V to 3.6 V	-	-	23	Ω
		I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	-	15	Ω
R _{ON(peak)}	switch ON-state resistance (peak)	V _S = GND to V _{CC} ; V _I = V _{IH}				
		I _S = 4 mA; V _{CC} = 1.65 V to 1.95 V	-	-	140	Ω
		I _S = 8 mA; V _{CC} = 2.3 V to 2.7 V	-	-	60	Ω
		I _S = 12 mA; V _{CC} = 2.7 V	-	-	38	Ω
		I _S = 24 mA; V _{CC} = 3 V to 3.6 V	-	-	30	Ω
		I _S = 32 mA; V _{CC} = 4.5 V to 5.5 V	-	-	23	Ω

[1] Typical values are measured at $T_{amb} = 25^\circ\text{C}$ and nominal V_{CC} .



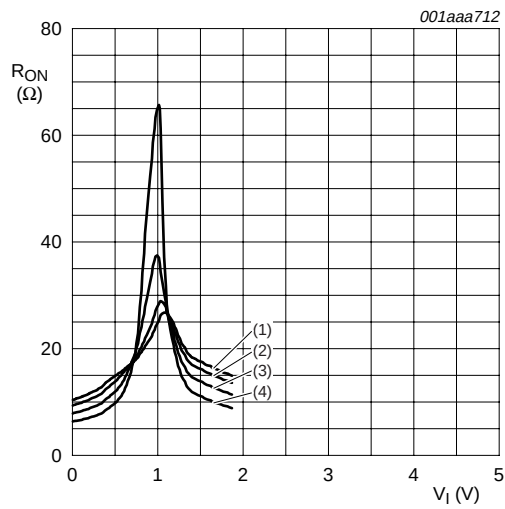
$V_I = \text{GND to } V_{CC}; R_{ON} = V_S/I_S.$

Fig 7. Test circuit for measuring switch ON-resistance

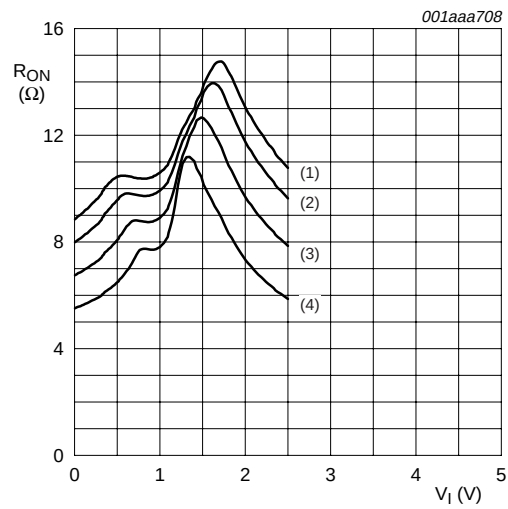


- (1) $V_{CC} = 1.8 \text{ V}$
 - (2) $V_{CC} = 2.5 \text{ V}$
 - (3) $V_{CC} = 2.7 \text{ V}$
 - (4) $V_{CC} = 3.3 \text{ V}$
 - (5) $V_{CC} = 5.0 \text{ V}$
- $V_S = \text{GND to } V_{CC}; T_{amb} = 25 \text{ }^\circ\text{C}.$

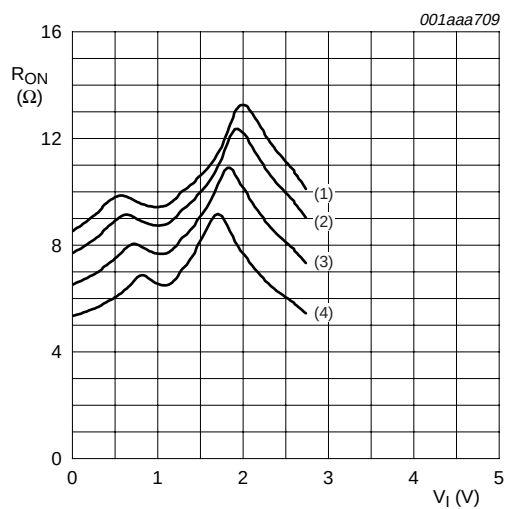
Fig 8. Typical switch ON-resistance as a function of input voltage



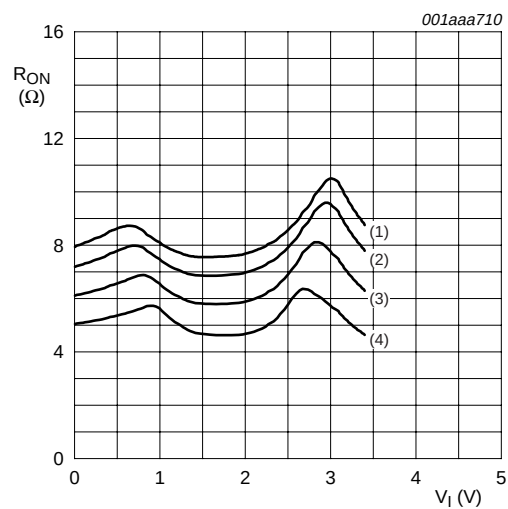
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}$
 (2) $T_{amb} = 85\text{ }^{\circ}\text{C}$
 (3) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 (4) $T_{amb} = -40\text{ }^{\circ}\text{C}$
 a. $V_{CC} = 1.8\text{ V}$



- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}$
 (2) $T_{amb} = 85\text{ }^{\circ}\text{C}$
 (3) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 (4) $T_{amb} = -40\text{ }^{\circ}\text{C}$
 b. $V_{CC} = 2.5\text{ V}$



- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}$
 (2) $T_{amb} = 85\text{ }^{\circ}\text{C}$
 (3) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 (4) $T_{amb} = -40\text{ }^{\circ}\text{C}$
 c. $V_{CC} = 2.7\text{ V}$



- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}$
 (2) $T_{amb} = 85\text{ }^{\circ}\text{C}$
 (3) $T_{amb} = 25\text{ }^{\circ}\text{C}$
 (4) $T_{amb} = -40\text{ }^{\circ}\text{C}$
 d. $V_{CC} = 3.3\text{ V}$

Fig 9. Switch ON-resistance as a function of input voltage

12. Dynamic characteristics

Table 10: Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); test circuit [Figure 13](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = −40 °C to +85 °C [1]						
t _{PHL} , t _{PLH}	propagation delay A to Bn or Bn to A	see Figure 10				
		V _{CC} = 1.65 V to 1.95 V	-	-	2	ns
		V _{CC} = 2.3 V to 2.7 V	-	-	1.2	ns
		V _{CC} = 2.7 V	-	-	1.0	ns
		V _{CC} = 3 V to 3.6 V	-	-	0.8	ns
		V _{CC} = 4.5 V to 5.5 V	-	-	0.6	ns
t _{PZH} , t _{PZL}	turn-on time S to Bn	see Figure 11				
		V _{CC} = 1.65 V to 1.95 V	1.0	8.7	14	ns
		V _{CC} = 2.3 V to 2.7 V	1.0	5.3	7.5	ns
		V _{CC} = 2.7 V	1.0	4.9	6.0	ns
		V _{CC} = 3 V to 3.6 V	0.5	4.0	5.5	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	3.0	4.0	ns
t _{PHZ} , t _{PLZ}	turn-off time S to Bn	see Figure 11				
		V _{CC} = 1.65 V to 1.95 V	2.5	6.0	8.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	4.4	6.0	ns
		V _{CC} = 2.7 V	1.5	4.2	5.0	ns
		V _{CC} = 3 V to 3.6 V	1.5	3.6	4.5	ns
		V _{CC} = 4.5 V to 5.5 V	0.8	2.9	3.5	ns
t _D	break-before-make time	see Figure 12 [2]				
		V _{CC} = 1.65 V to 1.95 V	0.5	-	-	ns
		V _{CC} = 2.3 V to 2.7 V	0.5	-	-	ns
		V _{CC} = 2.7 V	0.5	-	-	ns
		V _{CC} = 3 V to 3.6 V	0.5	-	-	ns
		V _{CC} = 4.5 V to 5.5 V	0.5	-	-	ns
T_{amb} = −40 °C to +125 °C						
t _{PHL} , t _{PLH}	propagation delay A to Bn or Bn to A	see Figure 10				
		V _{CC} = 1.65 V to 1.95 V	-	-	3.0	ns
		V _{CC} = 2.3 V to 2.7 V	-	-	2.0	ns
		V _{CC} = 2.7 V	-	-	1.5	ns
		V _{CC} = 3 V to 3.6 V	-	-	1.5	ns
		V _{CC} = 4.5 V to 5.5 V	-	-	1.0	ns

Table 10: Dynamic characteristics ...continued

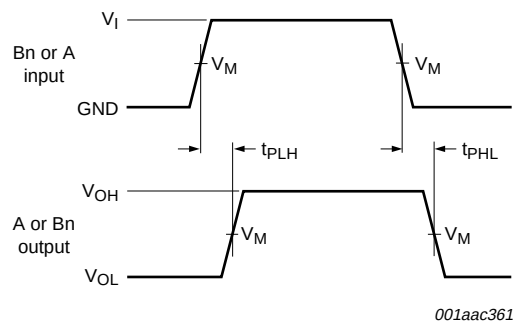
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); test circuit [Figure 13](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{\text{PZH}}, t_{\text{PZL}}$	turn-on time S to Bn	see Figure 11				
		$V_{\text{CC}} = 1.65 \text{ V to } 1.95 \text{ V}$	1.0	-	14.0	ns
		$V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$	1.0	-	7.5	ns
		$V_{\text{CC}} = 2.7 \text{ V}$	1.0	-	6.0	ns
		$V_{\text{CC}} = 3 \text{ V to } 3.6 \text{ V}$	0.5	-	5.5	ns
		$V_{\text{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$	0.5		4.0	ns
$t_{\text{PHZ}}, t_{\text{PLZ}}$	turn-off time S to Bn	see Figure 11				
		$V_{\text{CC}} = 1.65 \text{ V to } 1.95 \text{ V}$	2.5	-	8.5	ns
		$V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$	2.0	-	6.0	ns
		$V_{\text{CC}} = 2.7 \text{ V}$	1.5	-	5.0	ns
		$V_{\text{CC}} = 3 \text{ V to } 3.6 \text{ V}$	1.5	-	4.5	ns
		$V_{\text{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$	0.8	-	3.5	ns
t_{D}	break-before-make time	see Figure 12				
				[2]		
		$V_{\text{CC}} = 1.65 \text{ V to } 1.95 \text{ V}$	0.5	-	-	ns
		$V_{\text{CC}} = 2.3 \text{ V to } 2.7 \text{ V}$	0.5	-	-	ns
		$V_{\text{CC}} = 2.7 \text{ V}$	0.5	-	-	ns
		$V_{\text{CC}} = 3 \text{ V to } 3.6 \text{ V}$	0.5	-	-	ns
		$V_{\text{CC}} = 4.5 \text{ V to } 5.5 \text{ V}$	0.5	-	-	ns

[1] Typical values are measured at $T_{\text{amb}} = 25^\circ\text{C}$ and nominal V_{CC} .

[2] Break-before-make specified by design.

13. Waveforms



Measurement points are given in [Table 11](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig 10. Input (Bn or A) to output (A or Bn) propagation delays

Table 11: Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$

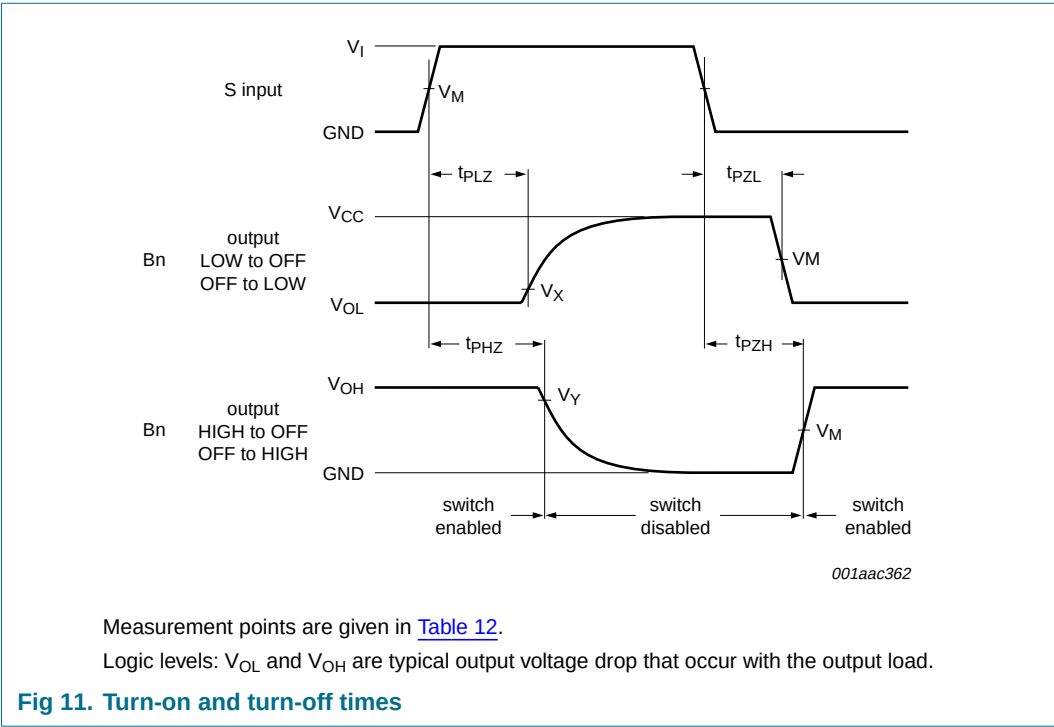


Table 12: Measurement points

Supply voltage	Input	Output		
V_{CC}	V_M	V_M	V_X	V_Y
1.65 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.3\text{ V}$	$V_{OH} - 0.3\text{ V}$



Supply voltage	Input		Load		V _{EXT}		
V _{CC}	V _I	t _r , t _f	C _L	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
1.65 V to 1.95 V	V _{CC}	≤ 2.0 ns	50 pF	500 Ω	open	GND	2V _{CC}
2.3 V to 2.7 V	V _{CC}	≤ 2.0 ns	50 pF	500 Ω	open	GND	2V _{CC}
2.7 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2V _{CC}
3 V to 3.6 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2V _{CC}
4.5 V to 5.5 V	V _{CC}	≤ 2.5 ns	50 pF	500 Ω	open	GND	2V _{CC}

14. Additional dynamic characteristics

Table 14: Additional dynamic characteristics

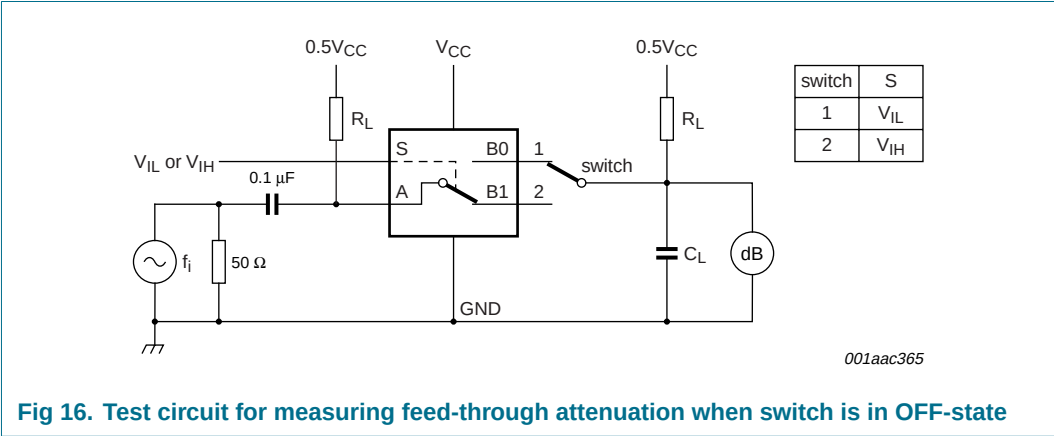
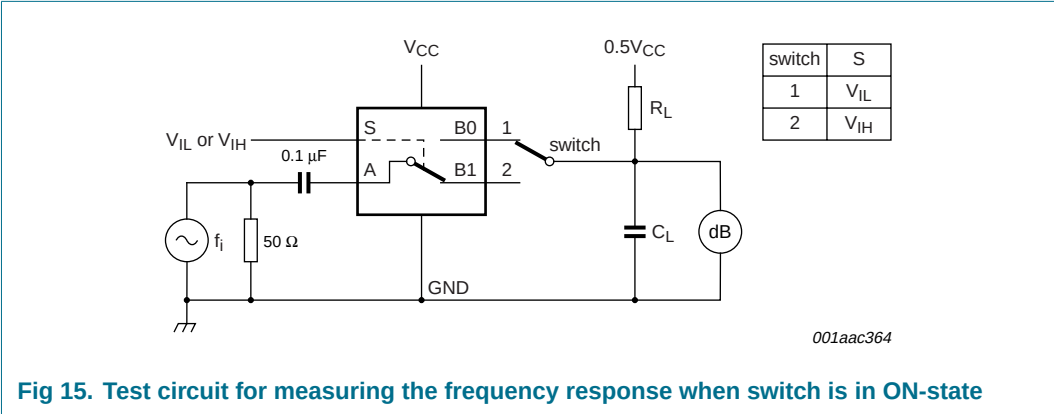
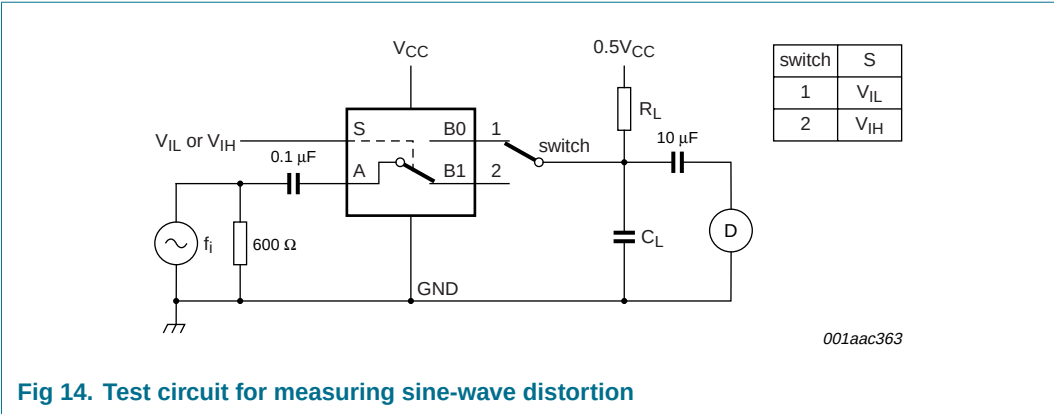
At recommended operating conditions; typical values measured at $T_{amb} = 25\text{ }^{\circ}\text{C}$.

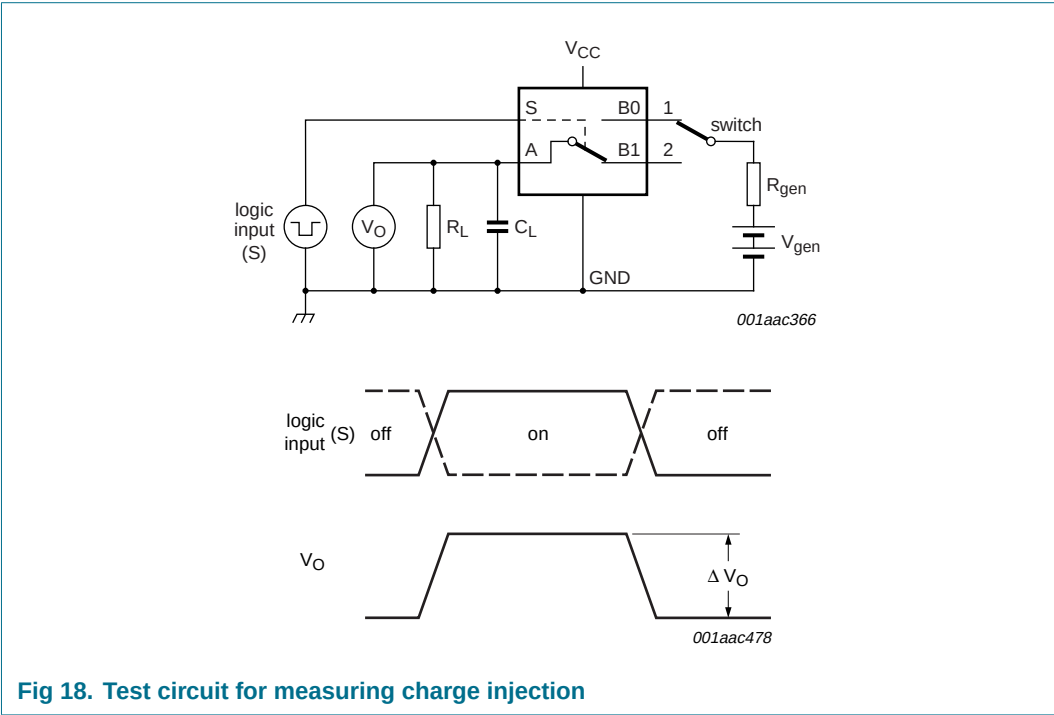
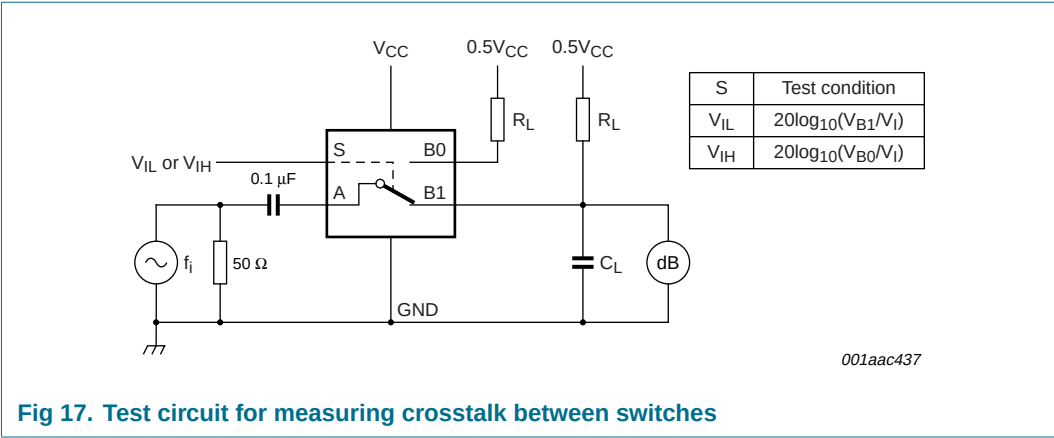
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
d_{sin}	sine-wave distortion	$f_i = 600\text{ Hz to }20\text{ kHz}$; $R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $V_I = 0.5\text{ V (p-p)}$; see Figure 14				
		$V_{CC} = 1.65\text{ V}$	-	0.260	-	%
		$V_{CC} = 2.3\text{ V}$	-	0.078	-	%
		$V_{CC} = 3.0\text{ V}$	-	0.078	-	%
		$V_{CC} = 4.5\text{ V}$	-	0.078	-	%
$f_{(-3dB)}$	switch ON-state signal frequency response	$R_L = 50\text{ }\Omega$; $C_L = 5\text{ pF}$; see Figure 15	[1]			
		$V_{CC} = 1.65\text{ V}$	-	200	-	MHz
		$V_{CC} = 2.3\text{ V}$	-	300	-	MHz
		$V_{CC} = 3.0\text{ V}$	-	300	-	MHz
		$V_{CC} = 4.5\text{ V}$	-	300	-	MHz
$\alpha_{OFF(ft)}$	switch OFF-state signal feed-through attenuation	$R_L = 50\text{ }\Omega$; $C_L = 5\text{ pF}$; $f_i = 10\text{ MHz}$; see Figure 16	[2]			
		$V_{CC} = 1.65\text{ V}$	-	-42	-	dB
		$V_{CC} = 2.3\text{ V}$	-	-42	-	dB
		$V_{CC} = 3.0\text{ V}$	-	-40	-	dB
		$V_{CC} = 4.5\text{ V}$	-	-40	-	dB
$V_{ct(sw-sw)}$	crosstalk between switches	$R_L = 50\text{ }\Omega$; $C_L = 5\text{ pF}$; $f_i = 10\text{ MHz}$; see Figure 17				
		$V_{CC} = 1.65\text{ V}$	-	-68	-	dB
		$V_{CC} = 2.3\text{ V}$	-	-70	-	dB
		$V_{CC} = 3.0\text{ V}$	-	-70	-	dB
		$V_{CC} = 4.5\text{ V}$	-	-70	-	dB
Q	charge injection	$C_L = 0.1\text{ nF}$; $V_{gen} = 0\text{ V}$; $R_{gen} = 0\text{ }\Omega$; $f = 1\text{ MHz}$; $R_L = 1\text{ M}\Omega$; see Figure 18	[3]			
		$V_{CC} = 1.8\text{ V}$	-	< 0.003	-	pC
		$V_{CC} = 2.5\text{ V}$	-	0.004	-	pC
		$V_{CC} = 3.3\text{ V}$	-	0.0045	-	pC
		$V_{CC} = 4.5\text{ V}$	-	0.0045	-	pC
		$V_{CC} = 5.5\text{ V}$	-	0.0045	-	pC

[1] Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.

[2] Adjust f_i voltage to obtain 0 dBm level at input.

[3] Definition: $Q = \Delta V_O \times C_L$. Guaranteed by design.





15. Package outline

Plastic surface mounted package; 6 leads

SOT363

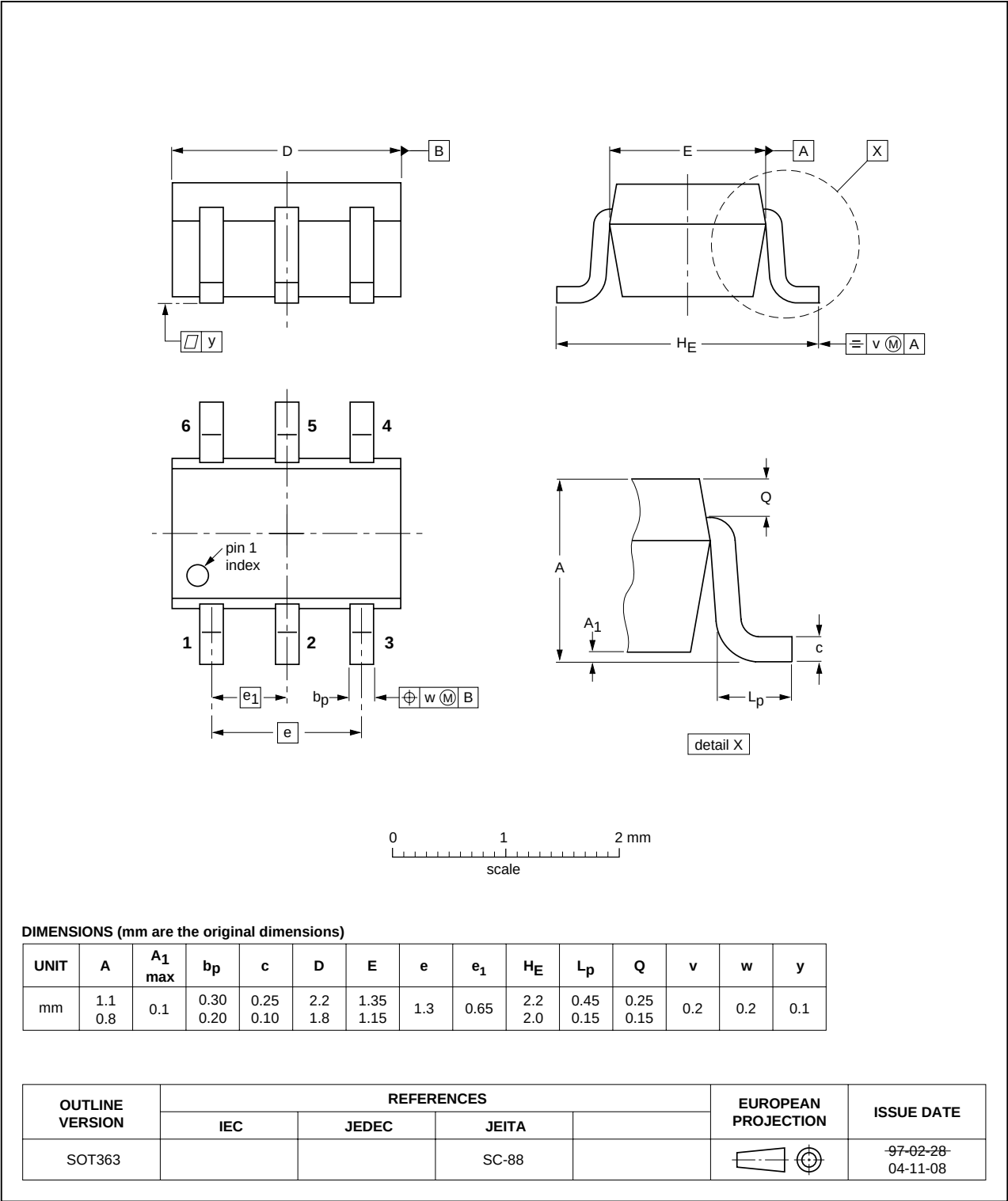
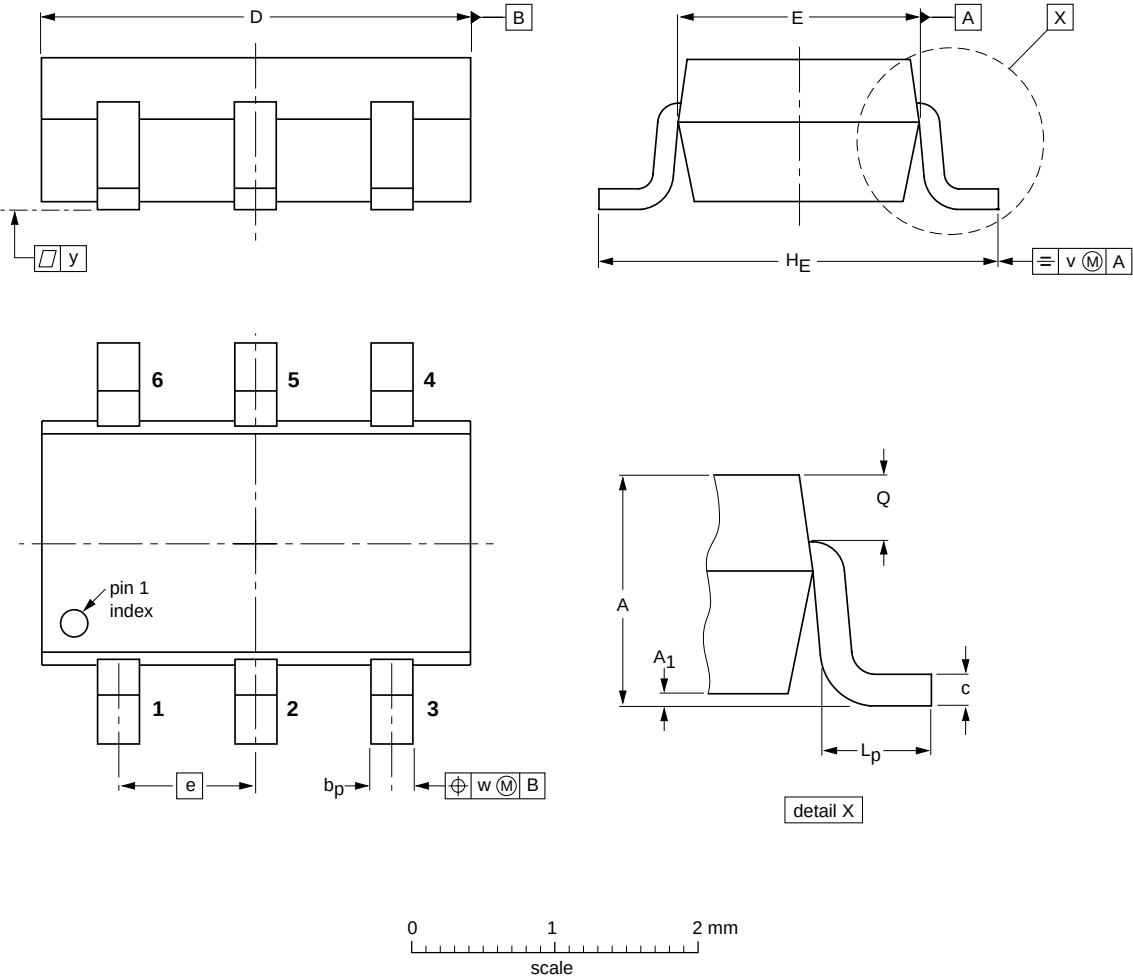


Fig 19. Package outline SOT363 (SC-88)

Plastic surface mounted package; 6 leads

SOT457



DIMENSIONS (mm are the original dimensions)

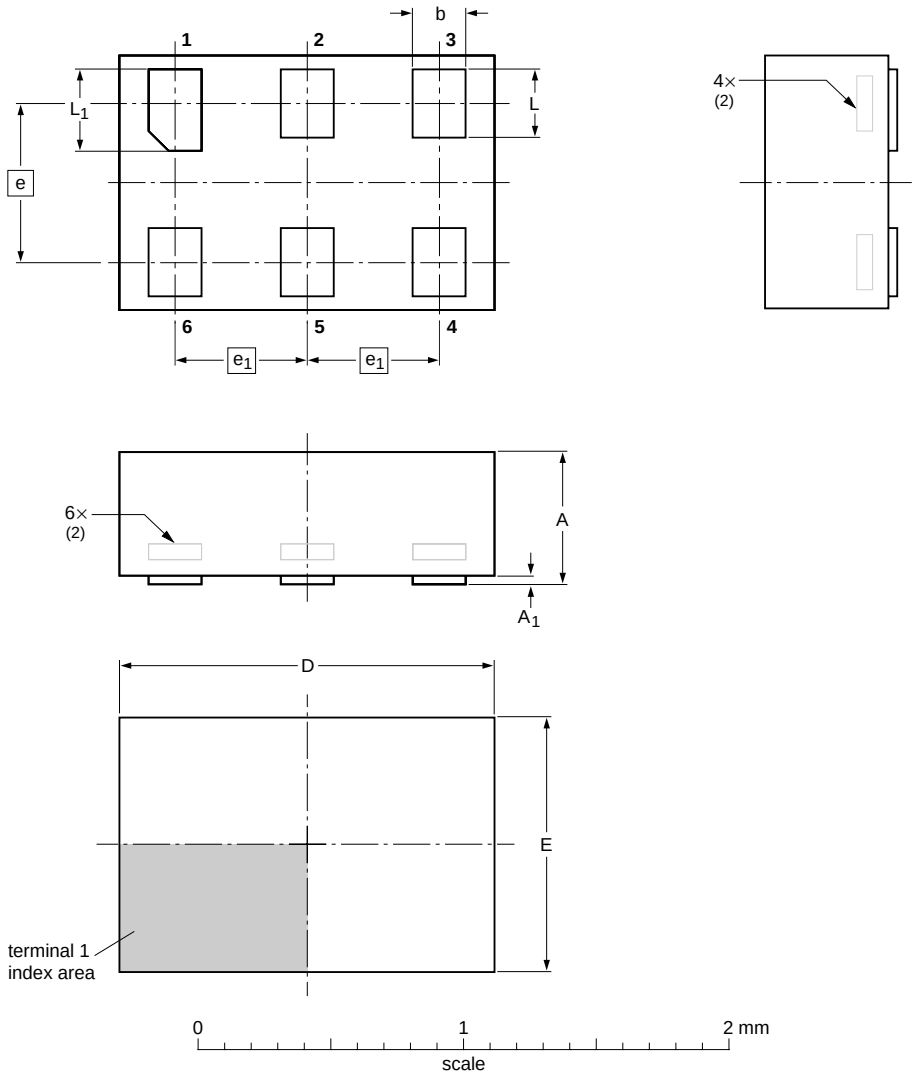
UNIT	A	A ₁	b _p	c	D	E	e	H _E	L _p	Q	v	w	y
mm	1.1 0.9	0.1 0.013	0.40 0.25	0.26 0.10	3.1 2.7	1.7 1.3	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT457			SC-74			-01-05-04 04-11-08

Fig 20. Package outline SOT457 (SC-74)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886



DIMENSIONS (mm are the original dimensions)

UNIT	A ⁽¹⁾ max	A ₁ max	b	D	E	e	e ₁	L	L ₁
mm	0.5	0.04	0.25 0.17	1.5 1.4	1.05 0.95	0.6	0.5	0.35 0.27	0.40 0.32

- Notes
1. Including plating thickness.
 2. Can be visible in some manufacturing processes.

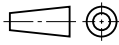
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT886		MO-252				-04-07-15 04-07-22

Fig 21. Package outline SOT886 (XSON6)

16. Revision history

Table 15: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
74LVC1G3157_1	20050207	Product data sheet	-	9397 750 14524	-

17. Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2] [3]}	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

18. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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